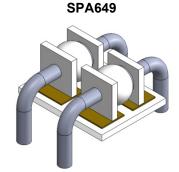


Solid State Devices, Inc. 14701 Firestone Blvd * La Mirada, Ca 90638 Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com	SF	SPA649-03 Series					
Designer's Data Sheet Part Number/Ordering Information ^{1/} SPA649- HF I I I Screening ^{2/} I I I Screening ^{2/} I I I TX = TX Level I I I TXV = TXV Level I I I S = S Level	30 AMP HYPERFAST CENTERTAP RECTIFIER BRIDGE 100 – 200 VOLTS 30 nsec						
Lead Bend Options = Straight Leads DB = Down Bend UB = Up Bend Reverse Recovery HF = Hyper Fast Recovery Voltage 01 = 100 Volts 02 = 150 Volts 03 = 200 Volts	 FEATURES: Hyper fast reverse recovery time: 30 ns max Hermetically sealed Void free construction eliminates die attach, wire bond, hermeticity and PIND issues related to TO-25X and stud mount packages Low reverse leakage current Electrically isolated baseplate Smaller footprint than TO-254 package Easy to configure as center tap, doubler or parallel connection Recommended replacement for 1N6657 – 1N6659 TX, TXV, and S-level screening available ^{2/} 						
MAXIMUM RATINGS ^{3/}		SYMBOL	VALUE	UNIT			
Peak Repetitive Reverse Voltage and DC Blocking Voltage	SPA649-01 SPA649-02 SPA649-03	V _{RRM} V _{RWM} V _R	100 150 200	Volts			
Average Rectified Forward Current Resistive load, 60Hz, Sine wave, T _C = 100°C	Per bridge Per leg	lo	30 15	Amps			
Peak Surge Current Non-repetitive, t = 8.3 ms half sine wave pulse, per leg		I _{FSM}	450	Amps			
Operating & Storage Temperature		T_J and T_{STG}	-65 to +175	°C			
Thermal Resistance, Junction to Case		$R_{\theta JC}$	1.9	°C/W			

NOTES:

1/ For ordering information, price, operating curves, and availability- contact factory.

- 2/ Screening based on MIL-PRF-19500. Screening flows available on request.
- $\underline{3}$ / Unless otherwise specified, all electrical characteristics @ 25°C.



SPA649-01 thru

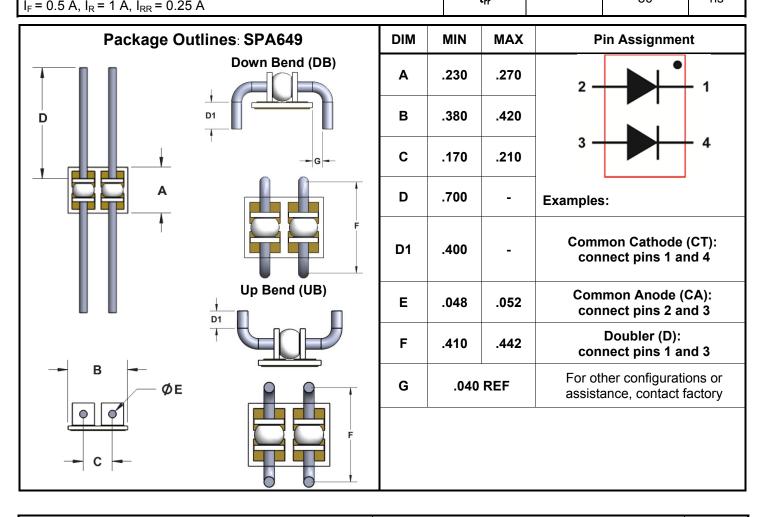


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SPA649-01 thru SPA649-03 Series

ELECTRICAL CHARACTERISTICS (per leg) ^{3/}							
CHARACTERISTICS		SYMBOL	TYP	LIMIT	UNIT		
Instantaneous Forward Voltage Drop 300 µs pulse	$I_F = 15 \text{ Adc}$ $I_F = 20 \text{ Adc}$ $I_F = 15 \text{ Adc}, T_A = +150^{\circ}\text{C}$ $I_F = 15 \text{ Adc}, T_A = +175^{\circ}\text{C}$	V _{F2}	0.90 0.70 0.67	0.95 1.00 0.86 	Vdc		
Reverse Leakage Current At rated V_R	T _A = +25°C T _A = +150°C T _A = +175°C	I _{R1} I _{R2} I _{R3}	0.1 50 300	2 500 	μA		
Breakdown Voltage I _R = 100 μA	SPA649-01 SPA649-02 SPA649-03	BV _R	 	110 160 210	V		
Junction Capacitance V _R = 10 Vdc, f = 1 MHz		C」	110	150	pF		
Isolation Leakage Current All terminals in common to base @ 1500V		R _{ISO}		1	μA		
Reverse Recovery Time		t _{rr}		30	ns		



NOTE: All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: PM0036A